

# 2MBI100XAA170-50

IGBT Modules

**Power Module (X series)**  
**1700V / 100A / 2-in-1 package**

■ **Features**

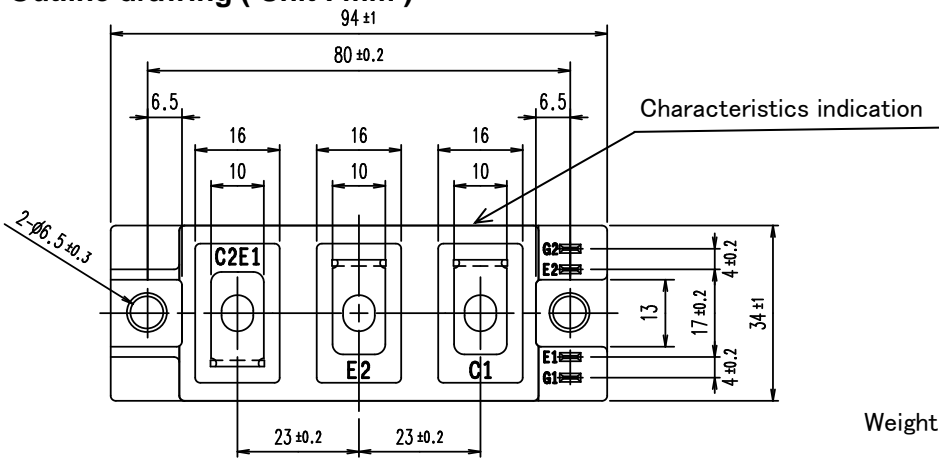
- LOW  $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

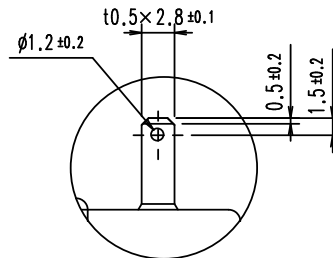
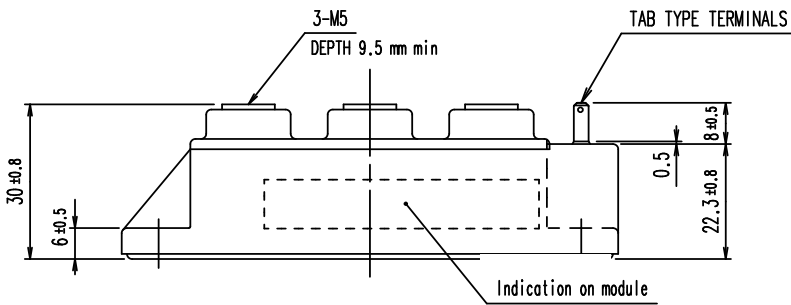
- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines



■ **Outline drawing ( Unit : mm )**

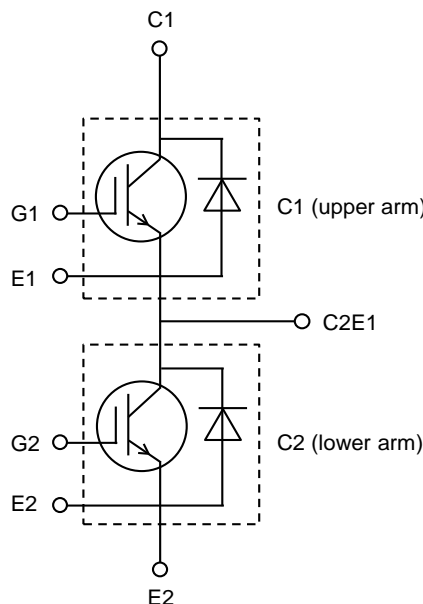


Weight: 180 g(typ.)



DETAIL TAB TYPE TERMINALS

■ **Equivalent Circuit**



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**IGBT Modules**
**■ Absolute Maximum Ratings (at  $T_C=25^\circ\text{C}$  unless otherwise specified)**

Items	Symbols	Conditions	Maximum Ratings	Units
Collector-Emitter voltage, Gate-Emitter short-circuited	$V_{CES}$		1700	V
Gate-Emitter voltage, Collector-Emitter short-circuited	$V_{GES}$		$\pm 20$	V
Collector current	$I_C$	Continuous   $T_C=100^\circ\text{C}$	100	A
Repetitive peak collector current	$I_{CRM}$	1ms	200	
Forward current	$I_F$	Continuous	100	
Repetitive peak forward current	$I_{FRM}$	1ms	200	
Total power dissipation	$P_{tot}$	1 device	560	W
Virtual junction temperature	$T_{vj}$		175	°C
Operating virtual junction temperature	$T_{vjop}$		175	
Case temperature	$T_C$		125	
Storage temperature	$T_{stg}$		-40 ~ 125	
Isolation voltage between terminals and copper base (*1)	$V_{isol}$	AC: 1min.	4000	Vrms
Mounting torque of screws to heatsink(*2)	$M_s$	M5 or M6	5.0	N·m
Mounting torque of screws to terminals(*3)	$M_t$	M5	5.0	

(\*1) All terminals should be connected together during the test.

(\*2) Recommendable Value: 3.0 ~ 5.0 N·m (M5 or M6)

(\*3) Recommendable Value: 2.5 ~ 5.0 N·m (M5)

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■ Electrical characteristics (at  $T_{vj}=25^{\circ}\text{C}$  unless otherwise specified)

	Symbols	Conditions	Characteristics			Units			
			min.	typ.	max.				
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 1700V$	-	-	50	$\mu\text{A}$			
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	100	nA			
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 100\text{mA}$	6.0	6.5	7.0	V			
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 100A$	$T_{vj}=25^{\circ}\text{C}$	-	1.70	2.15	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.65	2.10			
	$T_{vj}=125^{\circ}\text{C}$		-	2.00	-				
	$T_{vj}=150^{\circ}\text{C}$		-	2.10	-				
	$T_{vj}=175^{\circ}\text{C}$		-	2.20	-				
Internal Gate resistance	$r_g$	-	-	12.50	-	$\Omega$			
			Capacitance	$C_{ies}$	$V_{CE}=10V, V_{GE}=0V, f=1\text{MHz}$	-	14	-	nF
						$C_{oes}$	-	0.4	
$C_{res}$	-	0.08				-			
Gate charge	$Q_G$	$V_{CC} = 900V, I_C = 100A$ $V_{GE} = -15 \rightarrow +15V$	-	800	-	$\mu\text{C}$			
Forward voltage	$V_F$ (terminal)	$V_{GE} = 0V$ $I_F = 100A$	$T_{vj}=25^{\circ}\text{C}$	-	1.75	2.20	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.70	2.15			
	$T_{vj}=125^{\circ}\text{C}$		-	1.85	-				
	$T_{vj}=150^{\circ}\text{C}$		-	1.85	-				
	$T_{vj}=175^{\circ}\text{C}$		-	1.80	-				
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 900V$ $I_C, I_F = 100A$ $V_{GE} = \pm 15V$ $R_G = 3.3 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	405	-	ns		
			$T_{vj}=125^{\circ}\text{C}$	-	440	-			
			$T_{vj}=150^{\circ}\text{C}$	-	450	-			
			$T_{vj}=175^{\circ}\text{C}$	-	460	-			
	$t_r$		$T_{vj}=25^{\circ}\text{C}$	-	70	-			
			$T_{vj}=125^{\circ}\text{C}$	-	85	-			
			$T_{vj}=150^{\circ}\text{C}$	-	90	-			
			$T_{vj}=175^{\circ}\text{C}$	-	90	-			
	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	420	-			
			$T_{vj}=125^{\circ}\text{C}$	-	500	-			
			$T_{vj}=150^{\circ}\text{C}$	-	500	-			
			$T_{vj}=175^{\circ}\text{C}$	-	500	-			
	$t_f$		$T_{vj}=25^{\circ}\text{C}$	-	465	-			
			$T_{vj}=125^{\circ}\text{C}$	-	635	-			
			$T_{vj}=150^{\circ}\text{C}$	-	665	-			
			$T_{vj}=175^{\circ}\text{C}$	-	750	-			
Reverse recovery time	$t_{rr}$	$T_{vj}=25^{\circ}\text{C}$	-	820	-				
		$T_{vj}=125^{\circ}\text{C}$	-	1285	-				
		$T_{vj}=150^{\circ}\text{C}$	-	1390	-				
		$T_{vj}=175^{\circ}\text{C}$	-	1500	-				

(\*1) Turn-on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn-off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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**IGBT Modules**
**■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)**

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Switching loss (per pulse)	$E_{on}$	$V_{CC} = 900\text{V}$ $I_C, I_F = 100\text{A}$ $V_{GE} = \pm 15\text{V}$ $R_G = 3.3 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	21.8	-	mJ
			$T_{vj}=125^{\circ}\text{C}$	-	27.8	-	
			$T_{vj}=150^{\circ}\text{C}$	-	29.5	-	
			$T_{vj}=175^{\circ}\text{C}$	-	30.6	-	
	$E_{off}$		$T_{vj}=25^{\circ}\text{C}$	-	21.4	-	
			$T_{vj}=125^{\circ}\text{C}$	-	28.0	-	
			$T_{vj}=150^{\circ}\text{C}$	-	29.6	-	
			$T_{vj}=175^{\circ}\text{C}$	-	30.8	-	
	$E_{rr}$		$T_{vj}=25^{\circ}\text{C}$	-	11.8	-	
			$T_{vj}=125^{\circ}\text{C}$	-	20.8	-	
			$T_{vj}=150^{\circ}\text{C}$	-	24.1	-	
			$T_{vj}=175^{\circ}\text{C}$	-	27.7	-	

**NOTICE:**

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

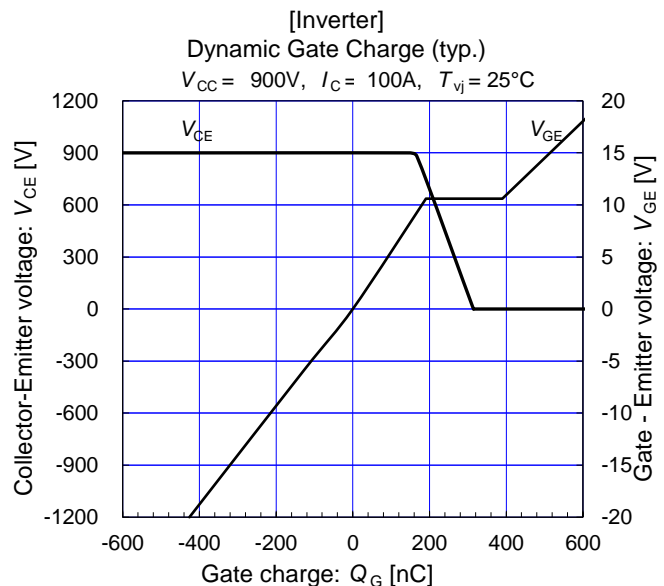
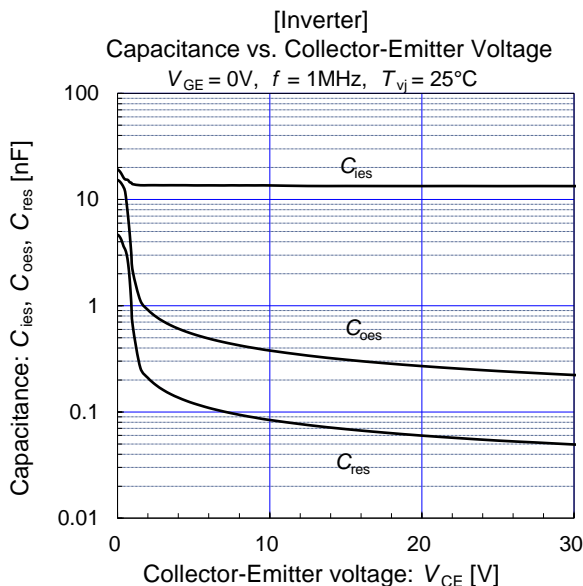
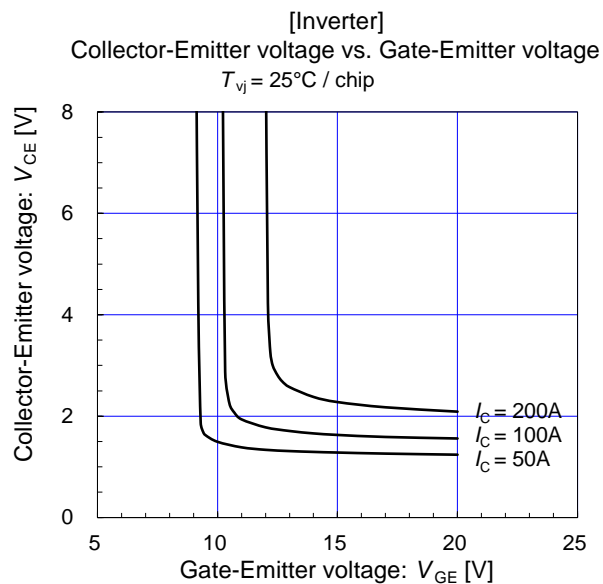
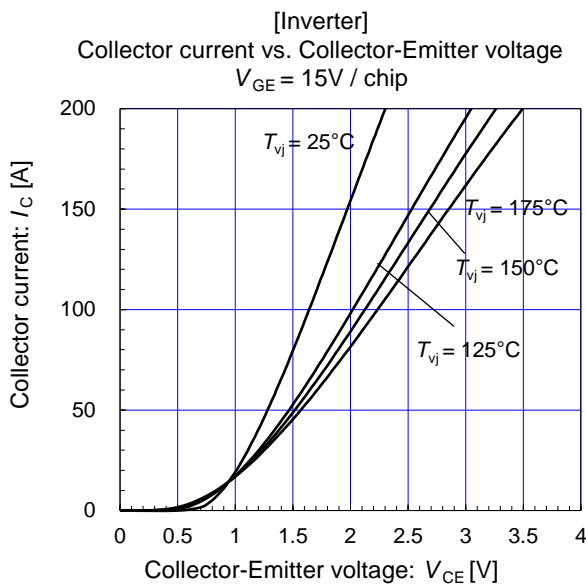
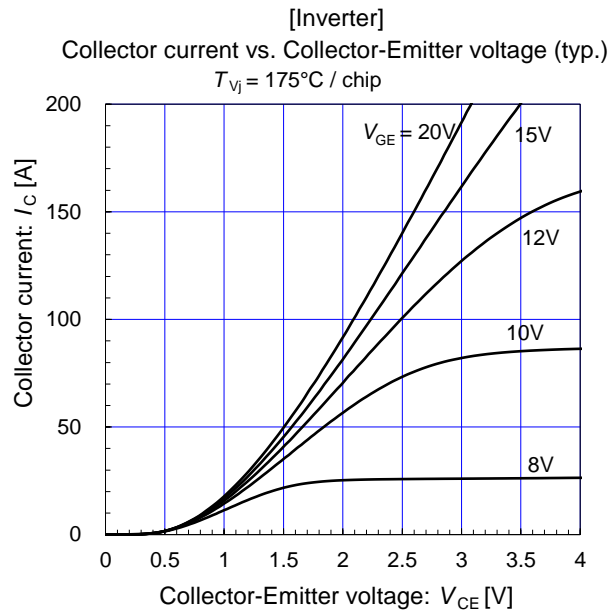
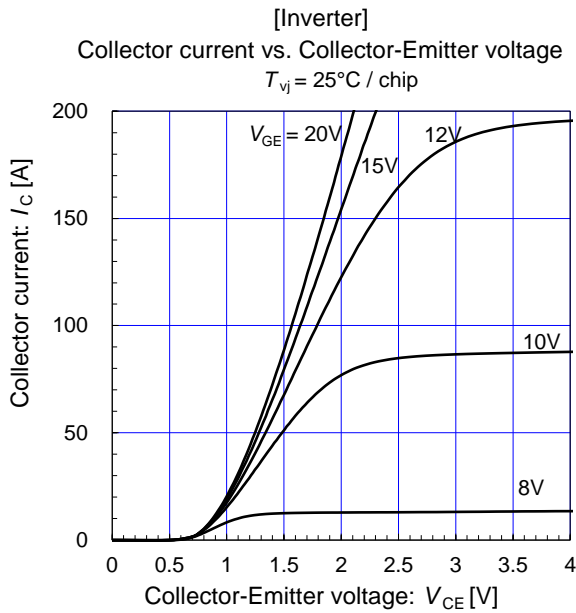
**■ Thermal resistance characteristics**

	Symbols	Conditions	Characteristics			ns
			min.	typ.	max.	
Thermal resistance (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.266	K/W
		Inverter FWD	-	-	0.446	
Thermal resistance case to heatsink (1IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.050	-	

(\*1) This is the value which is defined mounting on the additional heatsink with thermal grease.

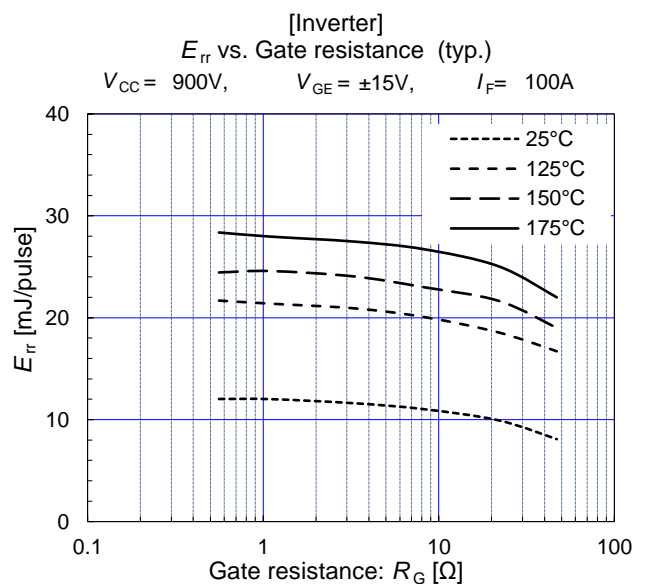
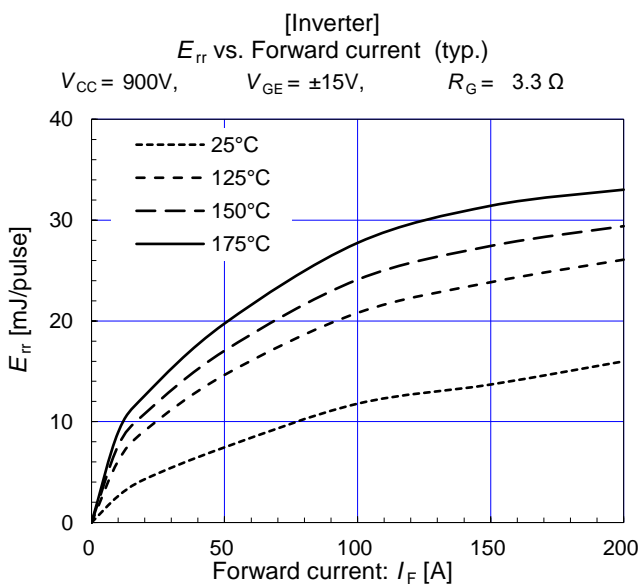
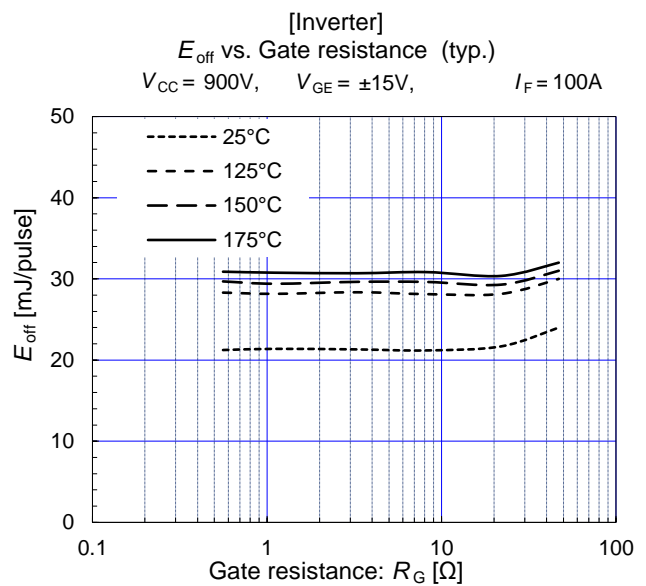
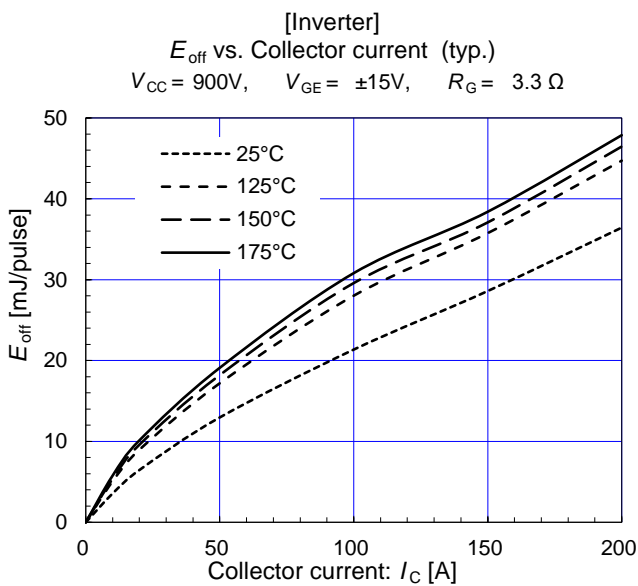
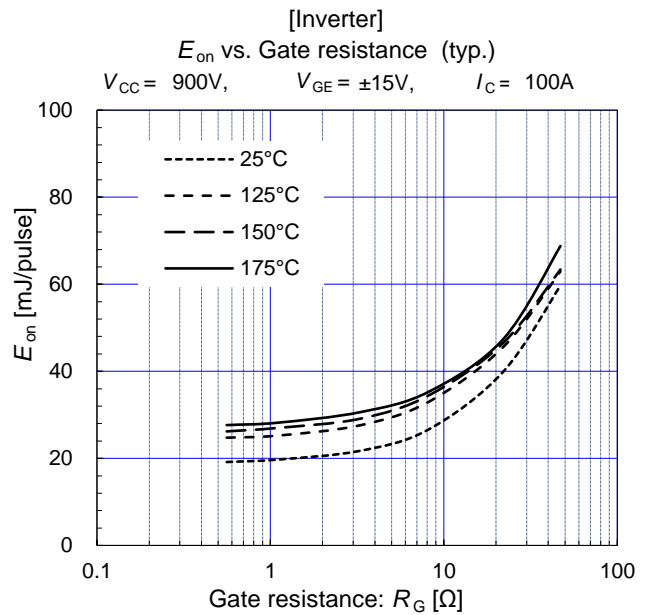
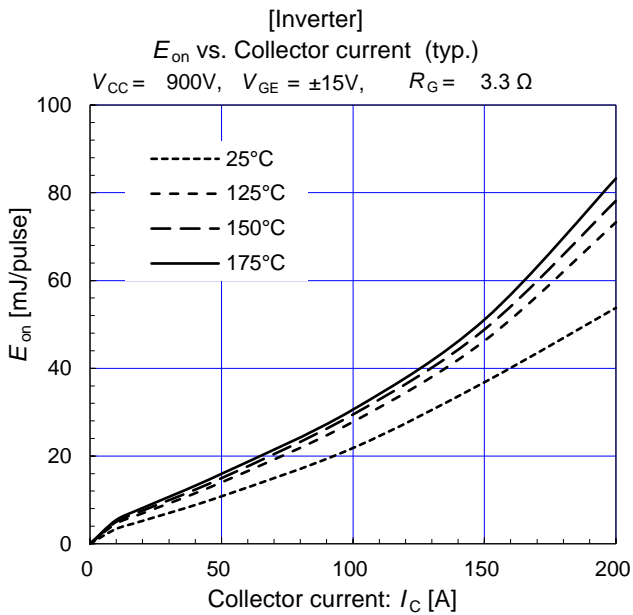
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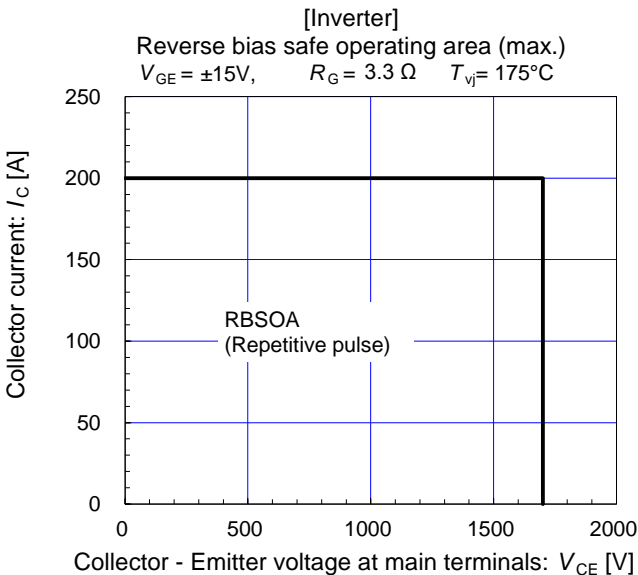
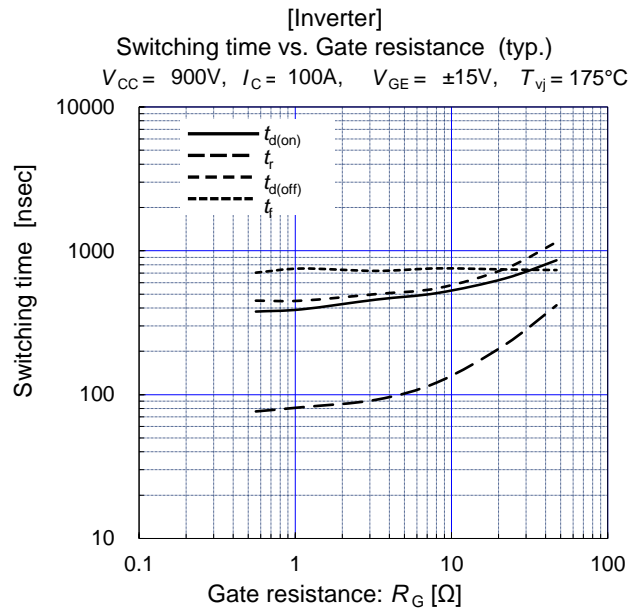
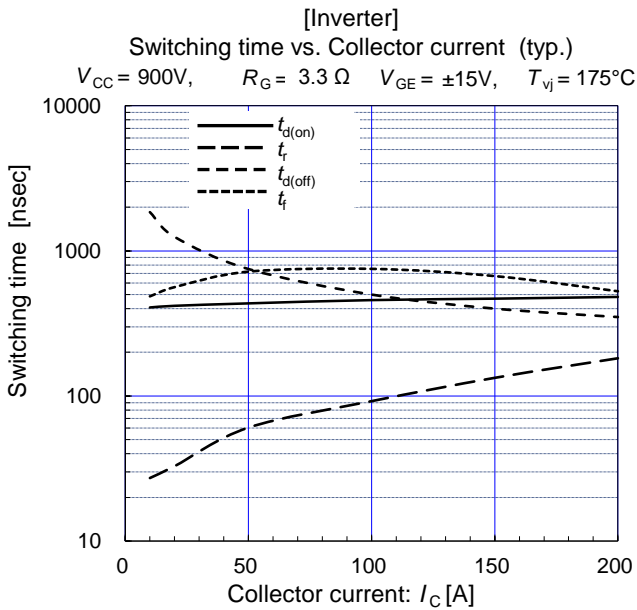
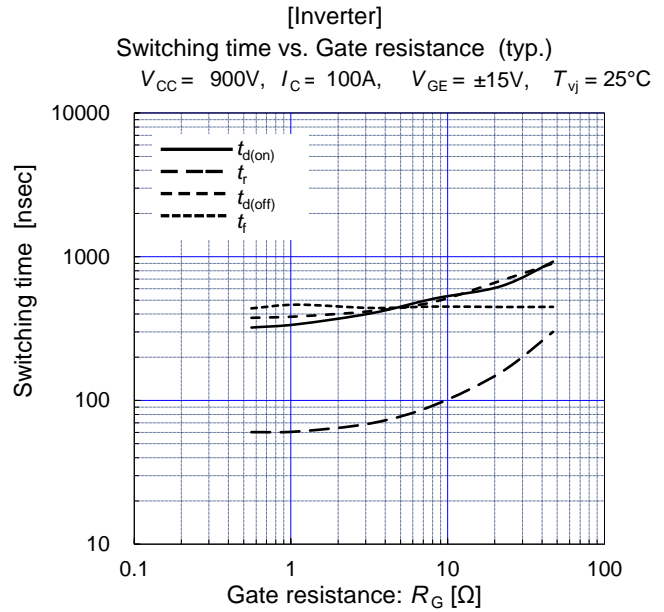
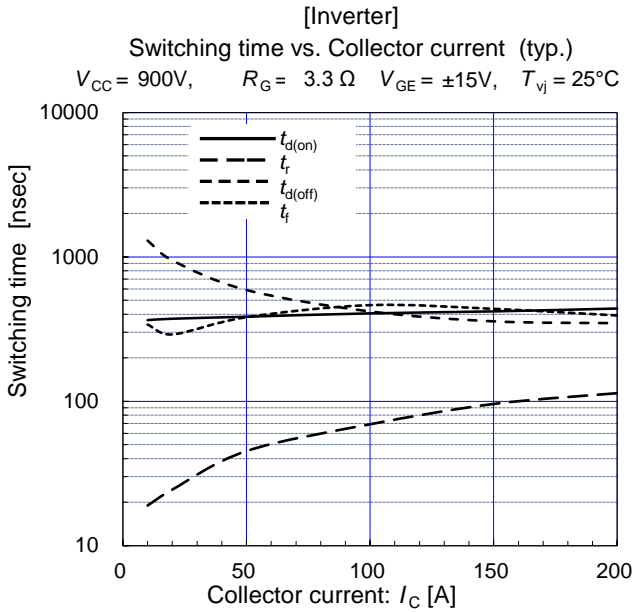


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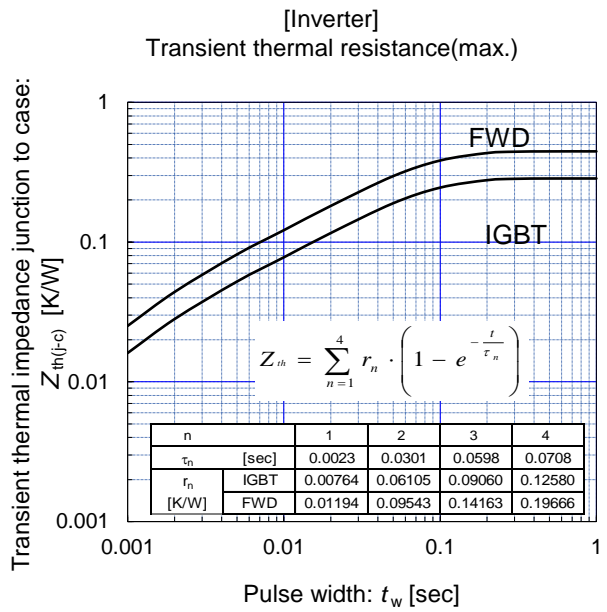
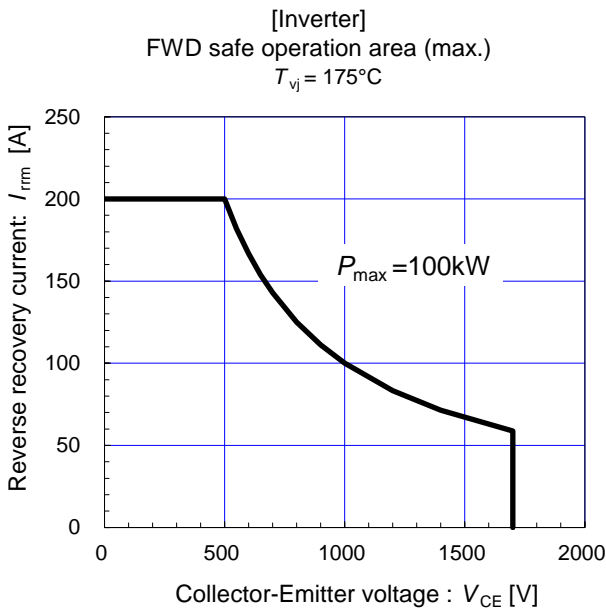
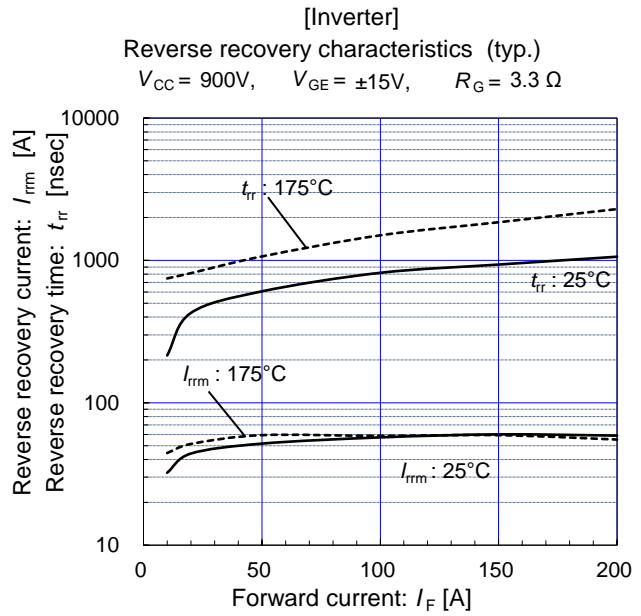
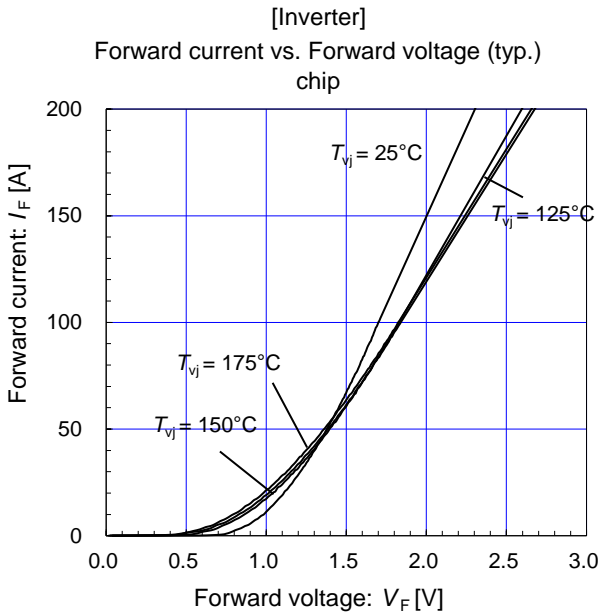


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